

MNLM108A-X REV 1A1

Original Creation Date: 06/26/95
Last Update Date: 02/11/99
Last Major Revision Date: 07/21/98

OPERATIONAL AMPLIFIERS
General Description

The LM108A is a precision operational amplifier having specifications a factor of ten better than FET amplifiers over a -55 C to +125 C temperature range.

The device operates with supply voltages from $\pm 2V$ to $\pm 20V$ and has sufficient supply rejection to use unregulated supplies. Although the circuit is interchangeable with, and uses the same compensation as, the LM101A, an alternate compensation scheme can be used to make it particularly insensitive to power supply noise, and to make supply bypass capacitors unnecessary.

The low current error of the LM108A makes possible many designs that are not practical with conventional amplifiers. In fact, it operates from 10 Mohms source resistances, introducing less error than devices such as the 709 with 10 Kohms sources. Integrators with drifts less than 500 $\mu V/sec$, and analog time delays in excess of one hour, can be made using capacitors no larger than 1 μF .

Industry Part Number

LM108A

Prime Die

LM108

NS Part Numbers

LM108AH/883
LM108AJ-8/883
LM108AJ/883
LM108AW/883
LM108AWG/883

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp Description		Temp (°C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- Maximum input bias current of 3.0 nA over temperature.
- Offset current less than 400 pA over temperature.
- Supply current of only 300 μ A, even in saturation.
- Guraranteed drift characteristics.

(Absolute Maximum Ratings)

(Note 1)

Supply Voltage		±20V
Input Voltage (Note 4)		±15V
Power Dissipation (Note 2)		500mW
Maximum Junction Temperature		150 °C
Differential Input Current (Note 3)		±10mA
Output Short-Circuit Duration		Continuous
Operating Temperature Range		-55 °C to +125 °C
Storage Temperature Range		-65 °C to +150 °C
Thermal Resistance		
ThetaJA		
METAL CAN	(Still Air)	159 °C/W
	(500LF/Min Air flow)	86 °C/W
CERDIP, 14 Lead	(Still Air)	94 °C/W
	(500LF/Min Air flow)	55 °C/W
CERDIP, 8 Lead	(Still Air)	123 °C/W
	(500LF/Min Air flow)	68 °C/W
CERPACK, 10 Lead	(Still Air)	225 °C/W
	(500LF/Min Air flow)	142 °C/W
CERAMIC SOIC	(Still Air)	225 °C/W
	(500LF/Min Air flow)	142 °C/W
ThetaJC		
METAL CAN		38 °C/W
CERDIP, 14 Lead		13 °C/W
CERDIP, 8 Lead		17 °C/W
CERPACK, 10 Lead		21 °C/W
CERAMIC SOIC		21 °C/W
Package Weight (Typical)		
METAL CAN		990mg
CERDIP, 14 Lead		2180mg
CERDIP, 8 Lead		1090mg
CERPACK, 10 Lead		225mg
CERAMIC SOIC		210mg
Lead Temperature		
(Soldering, 10 seconds)		260 °C
H-Pkg (Soldering, 10 seconds)		300 °C
ESD Tolerance (Note 5)		2000V

- Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{jmax} (maximum junction temperature), θ_{JA} (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is $P_{dmax} = (T_{jmax} - T_A)/\theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower.
- Note 3: The inputs are shunted with back-to-back diodes for overvoltage protection. Therefore, excessive current will flow if a differential input voltage in excess of 1V is applied between the inputs unless some limiting resistance is used.
- Note 4: For supply voltages less than $\pm 15V$, the absolute maximum input voltage is equal to the supply voltage.
- Note 5: Human body model, 1.5K Ohms in series with 100pF.

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{CC} = \pm 20V$, $V_{CM} = 0V$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Vio	Input Offset Voltage	$V_{CM} = -15V$			-0.5	0.5	mV	1
					-1.0	1.0	mV	2, 3
		$V_{CM} = 15V$			-0.5	0.5	mV	1
					-1.0	1.0	mV	2, 3
					-0.5	0.5	mV	1
					-1.0	1.0	mV	2, 3
		$V_{CC} = \pm 5V$			-0.5	0.5	mV	1
		$V_{CC} = \pm 5V$			-1.0	1.0	mV	2, 3
Iio	Input Offset Current	$V_{CM} = -15V$			-0.2	0.2	nA	1
					-0.4	0.4	nA	2, 3
		$V_{CM} = 15V$			-0.2	0.2	nA	1
					-0.4	0.4	nA	2, 3
					-0.2	0.2	nA	1
					-0.4	0.4	nA	2, 3
		$V_{CC} = \pm 5V$			-0.2	0.2	nA	1
		$V_{CC} = \pm 5V$			-0.4	0.4	nA	2, 3
Iib+	Input Bias Current	$V_{CM} = -15V$			-0.1	2	nA	1
					-1.0	3.0	nA	2
					-0.1	3.0	nA	3
		$V_{CM} = 15V$			-0.1	2	nA	1
					-1.0	3.0	nA	2
					-0.1	3.0	nA	3
					-0.1	2	nA	1
					-1.0	3.0	nA	2
					-0.1	3.0	nA	3
		$V_{CC} = \pm 5V$			-0.1	2	nA	1
		$V_{CC} = \pm 5V$			-1.0	3.0	nA	2
		$V_{CC} = \pm 5V$			-0.1	3.0	nA	3

Electrical Characteristics

DC PARAMETERS(Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{CC} = \pm 20V$, $V_{CM} = 0V$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
I _{ib} -	Input Bias Current	$V_{CM} = -15V$			-0.1	2	nA	1
					-1.0	3.0	nA	2
					-0.1	3.0	nA	3
		$V_{CM} = 15V$			-0.1	2	nA	1
					-1.0	3.0	nA	2
					-0.1	3.0	nA	3
					-0.1	2	nA	1
					-1.0	3.0	nA	2
					-0.1	3.0	nA	3
		$V_{CC} = \pm 5V$			-0.1	2	nA	1
		$V_{CC} = \pm 5V$			-1.0	3.0	nA	2
		$V_{CC} = \pm 5V$			-0.1	3.0	nA	3
PSRR	Power Supply Rejection Ratio	$\pm 20V \leq V_{CC} \leq \pm 5V$			96		dB	1, 2, 3
CMRR	Common Mode Rejection Ratio	$-15V \leq V_{CM} \leq 15V$			96		dB	1, 2, 3
I _{os} +	Short Circuit	$V_{CC} = \pm 15V$			-30	-1.0	mA	1, 2, 3
I _{os} -	Short Circuit	$V_{CC} = \pm 15V$			1	30	mA	1, 2, 3
I _{cc}	Power Supply Current					0.6	mA	1
						0.4	mA	2
						0.8	mA	3
R _{in}	Input Resistance		2		30		M	1
V _{in}	Input Voltage Range	$V_{CC} = \pm 15V$	1		± 14		V	1, 2
		$V_{CC} = \pm 15V$	1		± 13.5		V	3
			1		± 15		V	1, 2, 3
Delta V _{io} /Delta T	Temperature Coefficient of Input Offset Voltage		2			5	uV/C	1, 2, 3
Delta I _{io} /Delta T	Temperature Coefficient of Input Offset Current		2			2.5	pA/C	1, 2, 3

Electrical Characteristics

DC PARAMETERS(Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{CC} = \pm 20V$, $V_{CM} = 0V$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Vop+	Output Voltage Swing	$V_{CC} = \pm 15V$, $R_L = 10K \text{ Ohms}$			13		V	4, 5, 6
Vop-	Output Voltage Swing	$V_{CC} = \pm 15V$, $R_L = 10K \text{ Ohms}$				-13	V	4, 5, 6
Avs+	Open Loop Voltage Gain	$V_{CC} = \pm 15V$, $R_L = 10K \text{ Ohms}$, $V_{out} = 0 \text{ to } 10V$	3		80		V/mV	4
		$V_{CC} = \pm 15V$, $R_L = 10K \text{ Ohms}$, $V_{out} = 0 \text{ to } 10V$	3		40		V/mV	5, 6
Avs-	Open Loop Voltage Gain	$V_{CC} = \pm 15V$, $R_L = 10K \text{ Ohms}$, $V_{out} = 0 \text{ to } -10V$	3		80		V/mV	4
		$V_{CC} = \pm 15V$, $R_L = 10K \text{ Ohms}$, $V_{out} = 0 \text{ to } -10V$	3		40		V/mV	5, 6
TR	Transient Response Rise Time		2		1		μS	7

DC PARAMETERS: DRIFT VALUES

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{CC} = \pm 20V$, $V_{CM} = 0V$. "Deltas not required on B-Level product. Deltas required for S-Level product ONLY as specified on Internal Processing Instructions (IPI)."

Vio	Input Offset Voltage	$V_{CM} = 15V$			-0.25	0.25	mV	1
Iib+	Input Bias Current	$V_{CM} = 15V$			-1	1	nA	1
Iib-	Input Bias Current	$V_{CM} = 15V$			-1	1	nA	1

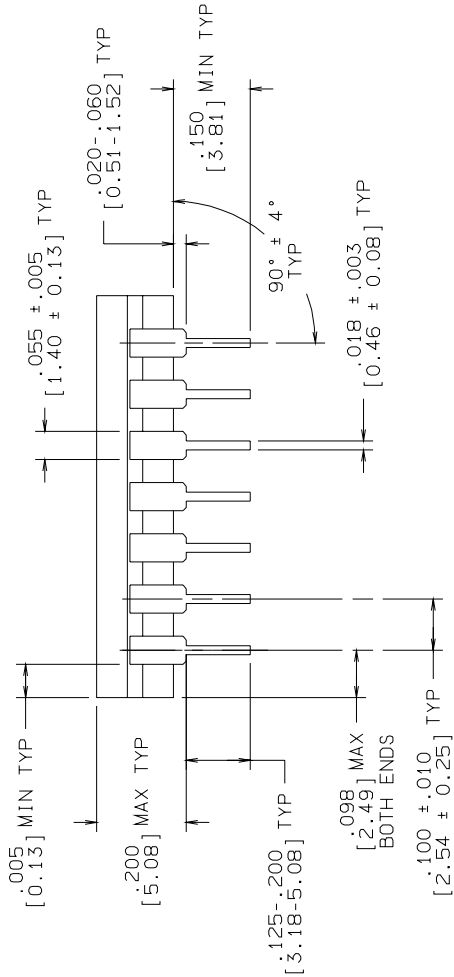
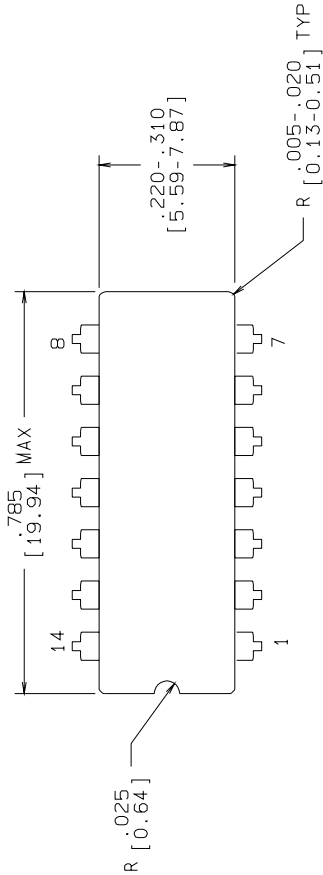
Note 1: Parameter tested go-no-go only.
 Note 2: Guaranteed parameter not tested.
 Note 3: Datalog in K = V/mV.

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
06135HRA2	CERPACK (W), 10 LEAD (B/I CKT)
09556HR02	CERDIP (J), 14 LEAD (B/I CKT)
09557HRA4	METAL CAN (H), TO-99, 8LD, .200 DIA P.C. (B/I CKT)
H08CRF	METAL CAN (H), TO-99, 8LD, .200 DIA P.C. (P/P DWG)
J08ARL	CERDIP (J), 8 LEAD (P/P DWG)
J14ARH	CERDIP (J), 14 LEAD (P/P DWG)
P000253A	CERAMIC SOIC (WG), 10 LEAD (PINOUT)
P000310A	METAL CAN (H), TO-99, 8LD, .200 DIA P.C. (PINOUT)
P000311A	CERDIP (J), 14 LEAD (PINOUT)
P000312A	CERDIP (J), 8 LEAD (PINOUT)
P000431A	CERPACK (W), 10 LEAD (PINOUT)
W10ARG	CERPACK (W), 10 LEAD (P/P DWG)
WG10ARC	CERAMIC SOIC (WG), 10 LEAD (P/P DWG)

See attached graphics following this page.

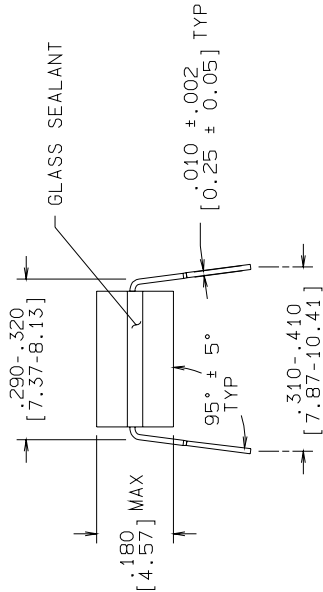
R E V I S I O N S				
LTR	DESCRIPTION	E.C.N.	DATE	BY/APP'D
H	REVISE PER CURRENT STD; REDRAW	10001	09/15/93	TL/



CONTROLLING DIMENSION: INCH

NOTES: UNLESS OTHERWISE SPECIFIED

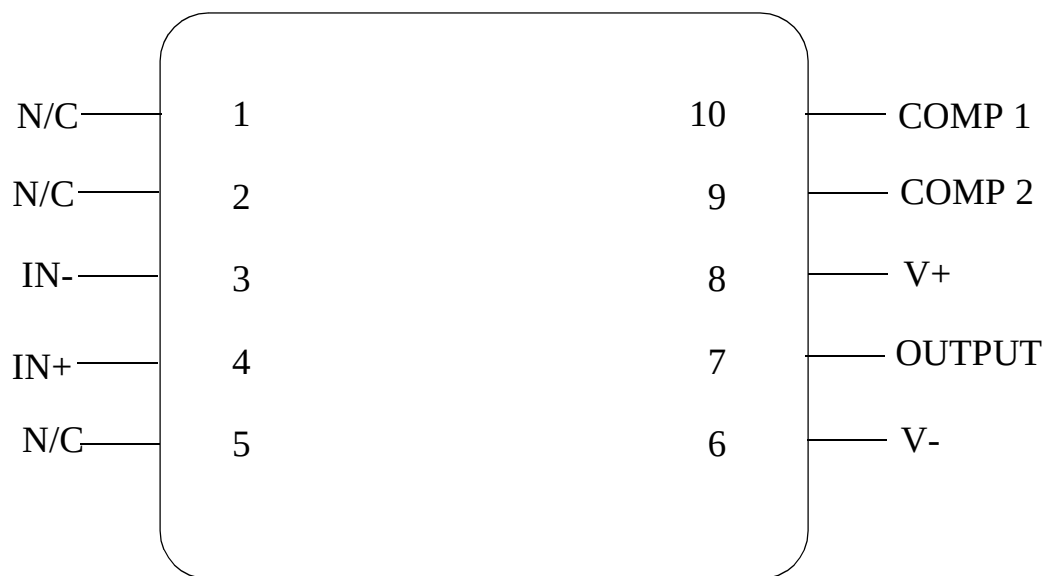
1. LEAD FINISH TO BE 200 MICROMETERS / 5.08 MICROMETERS MINIMUM SOLDER MEASURED AT THE CREST OF THE MAJOR FLATS.
2. JEDEC REGISTRATION MO-036, VARIATION AB, DATED 04/1981.



MIL/AERO MIL-M-38510
CONFIGURATION CONTROL CONFIGURATION CONTROL

APPROVALS	DATE	NATIONAL SEMICONDUCTOR CORPORATION	
DRAWN LEQUANG	09/15/93	2900 Semiconductor Drive, Santa Clara, CA 95052-8090	
DFTG. CHK.			
ENGR. CHK.			
APPROVAL			
		SCALE	DRAWING NUMBER
		N/A	MKT-J14A
		DO NOT SCALE	SHEET 1 OF 1
			REV H

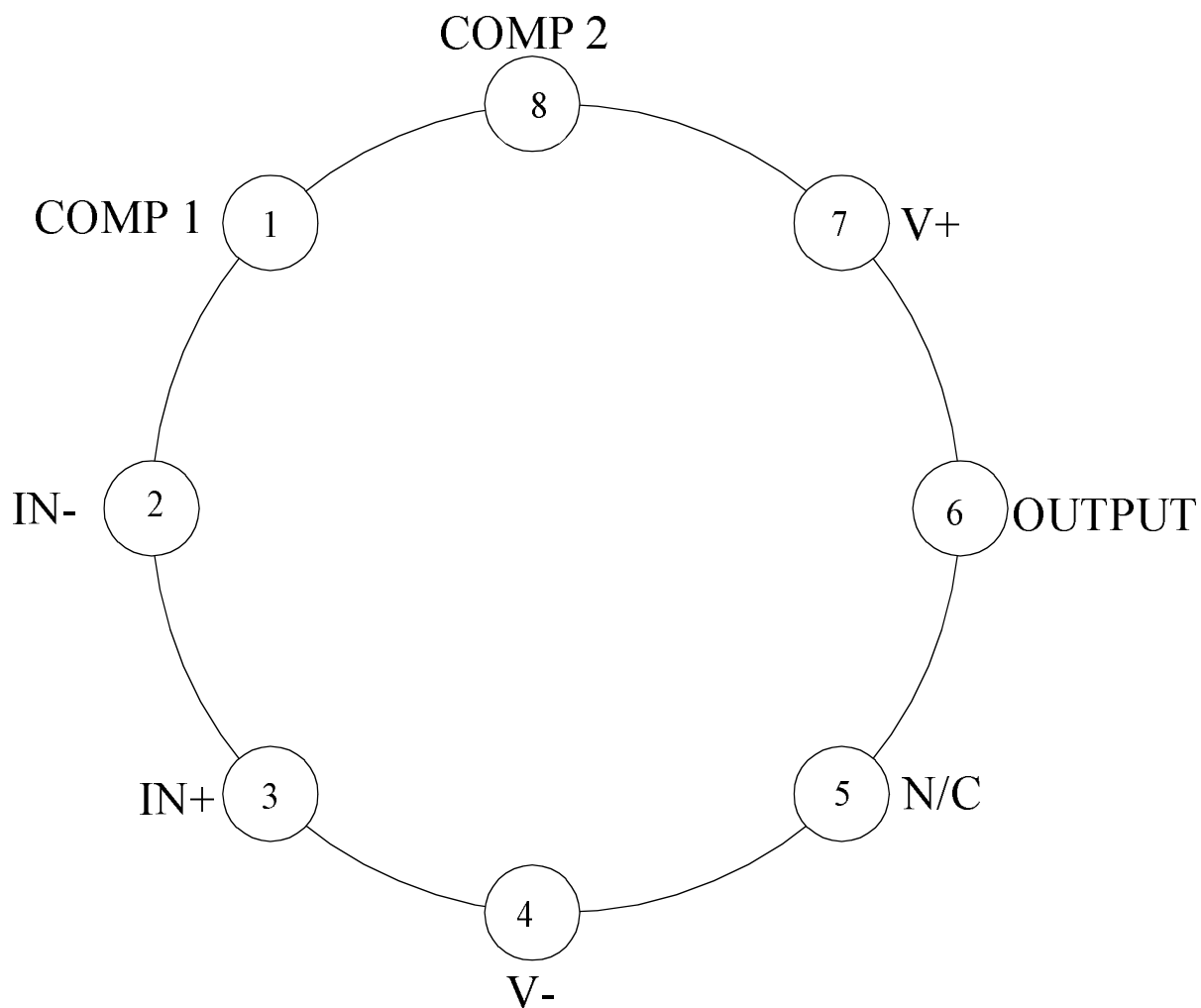
CERDIP (J) ,
14 LEAD,



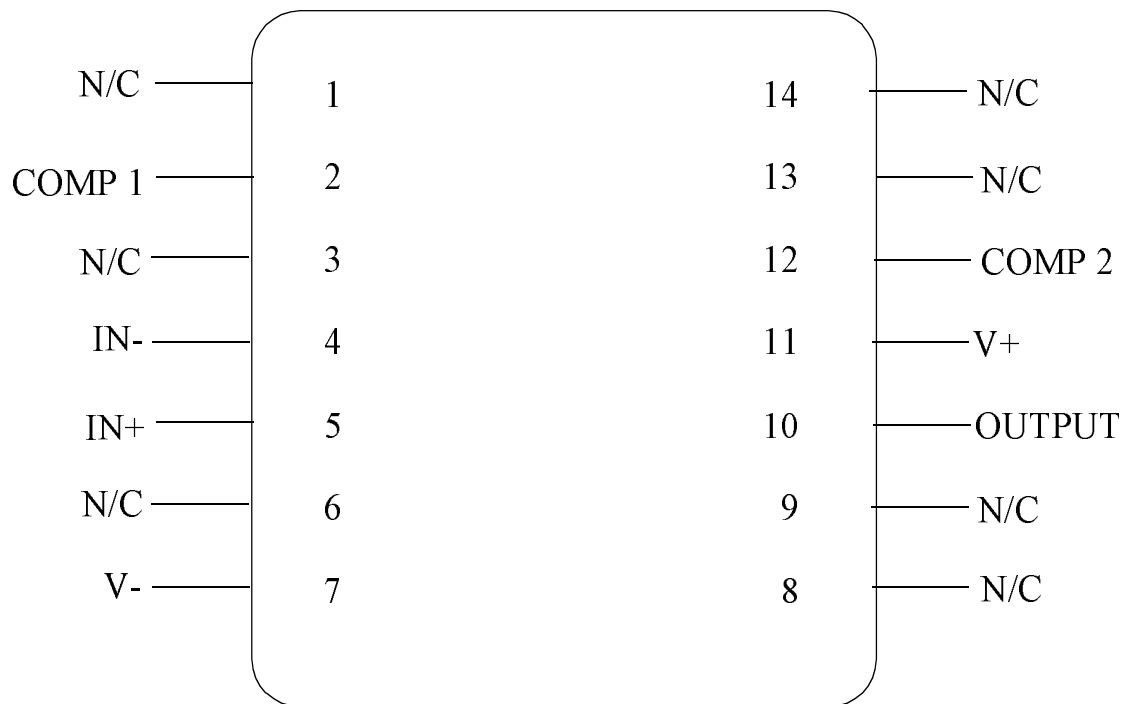
LM108AWG
10 - LEAD CERAMIC SOIC
CONNECTION DIAGRAM
TOP VIEW
P000253A



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LM108AH, LM108H
8 - PIN METAL CAN
CONNECTION DIAGRAM
TOP VIEW
P000310A



LM108AJ, LM108J
 14 - LEAD DIP
 CONNECTION DIAGRAM
 TOP VIEW
 P000311A



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 2900 SEMICONDUCTOR DRIVE
 SANTA CLARA, CA 95050



LM108AJ-8, LM108J-8

8 - LEAD DIP

CONNECTION DIAGRAM

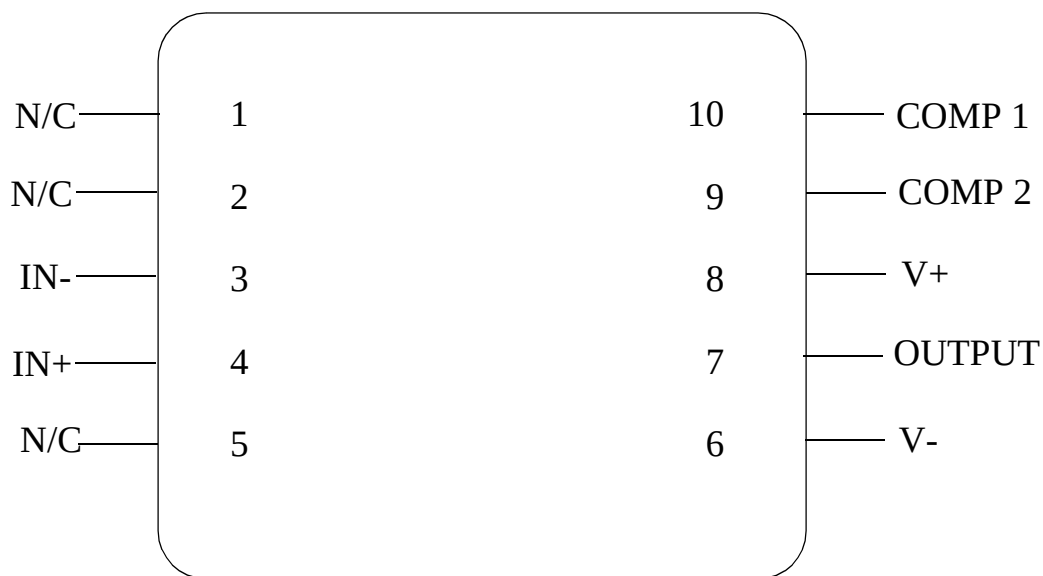
TOP VIEW

P000312A



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2900 SEMICONDUCTOR DRIVE
SANTA CLARA, CA 95050

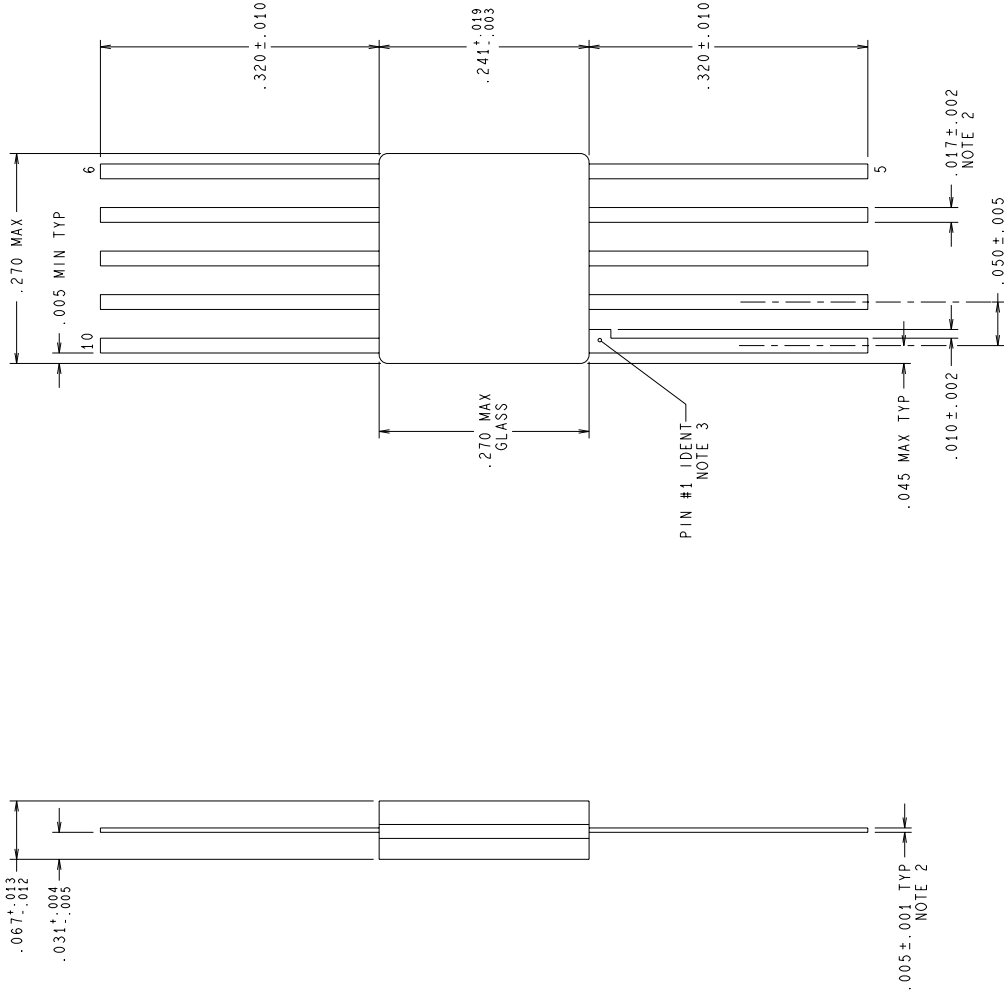


LM108AW
10 - LEAD CERPACK
CONNECTION DIAGRAM
TOP VIEW
P000431A



National Semiconductor™
MIL/AEROSPACE OPERATIONS
2900 SEMICONDUCTOR DRIVE
SANTA CLARA, CA 95050

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
F	REVISE AND REDRAW PER NEW STANDARD.	10510	07/28/94
G	.017±.002 WAS .017±.020.	10654	10/21/94



NOTES: UNLESS OTHERWISE SPECIFIED.

1. LEAD FINISH: SOLDER DIPPED WITH Sn60 OR Sn63 SOLDER CONFORMING TO MIL-M-38510 TO A MINIMUM THICKNESS OF 200 MICROINCHES. SOLDER MAY BE APPLIED OVER LEAD BASIS METAL OR Sn PLATE.
2. MAXIMUM LIMIT MAY BE INCREASED BY .003 INCHES AFTER LEAD FINISH APPLIED.
3. LEAD 1 IDENTIFICATION SHALL BE:
a) A NOTCH OR OTHER MARK WITHIN THIS AREA
b) A TAB ON LEAD 1, EITHER SIDE
4. REFERENCE JEDEC REGISTRATION M0-003, VARIATION AG, DATED 06/01/76.

MIL/AERO
CONFIGURATION CONTROL

MIL-M-38510
CONFIGURATION CONTROL

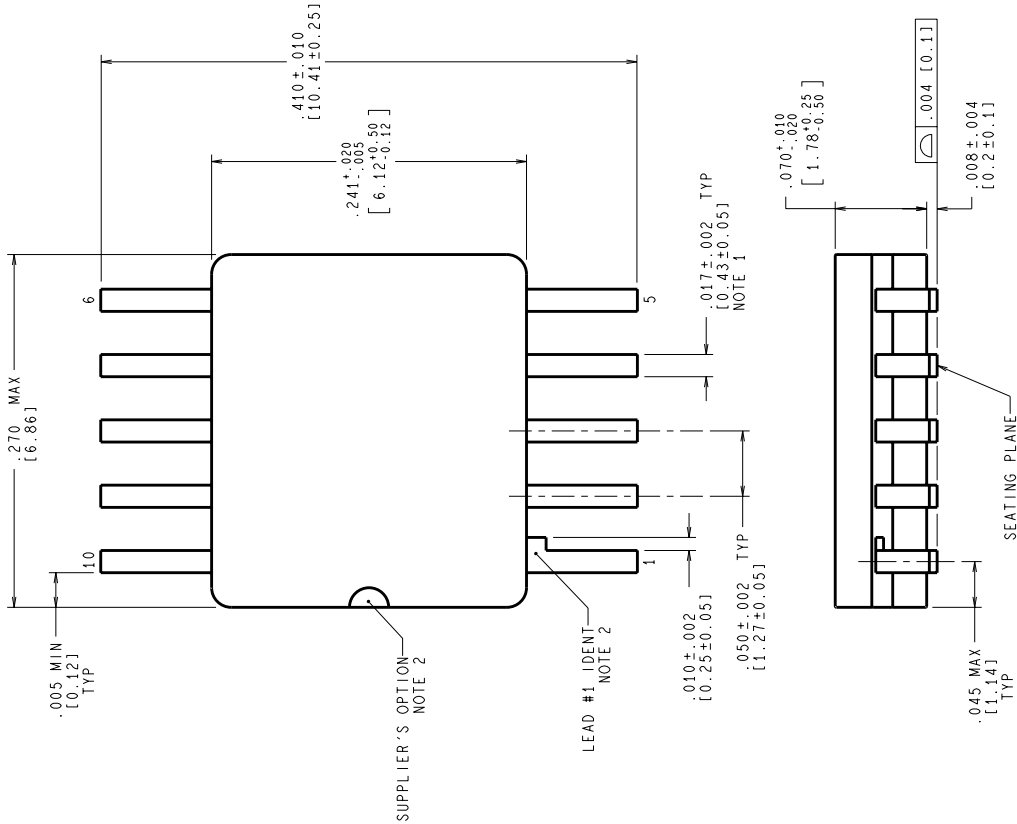
APPROVALS		DATE	
DRN	<i>D. F. Grady</i>		07/28/94
DFTG. CHK.			
EMR. CHK.			
PROJECTION			
DO NOT SCALE DRAWING		SCALE	N/A
		SIZE	C
		DRAWING NUMBER	MKT-W10A
		REV	G
		SHEET 1 of 1	

National Semiconductor
2000 Semiconductor dr., Santa Clara, CA 95052-8090

CERPACK, 10 LEAD

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
A	RELEASE TO DOCUMENT CONTROL	11374	02/29/1996
B	LD PITCH TOL WAS $\pm .005$; CHANGE LD RADIUS TO REF DIM; REMOVE THE OTHER R .006 $\pm .002$ DIM .040 $\pm .003$ WAS .037 $\pm .003$	11441	04/19/1996
C	R .015(0.38) WAS R .006(0.15)	11838	10/08/1997

BY/APP'D	DATE	MS/KH



CONTROLLING DIMENSION IS INCH
VALUES IN | | ARE MILLIMETERS

MIL-PRF-38535 CONFIGURATION CONTROL

APPROVALS	DATE	SCALE	SIZE	DRAWING NUMBER	REV
DESIGN MARTY SUCHY	02/29/96	N/A	C	(SC)MKT-WG10A	C
ENGINEER CHK.					
TESTER CHK.					
PROJECTION 					
DO NOT SCALE DRAWING SHEET 1 of 1					

National Semiconductor
2000 Semiconductor Dr., Santa Clara, CA 95052-8000

**CERPACK,
10 LEAD,
GULL WING**

NOTES: UNLESS OTHERWISE SPECIFIED

- LEAD FINISH: SOLDER DIPPED WITH Sn60 OR Sn63 SOLDER CONFORMING TO MIL-PRF-38535 TO A MINIMUM THICKNESS OF 200 MICRONS/ 5.08 MICROMETERS. SOLDER MAY BE APPLIED OVER LEAD BASES METAL OR Sn PLATE. MAXIMUM LIMIT MAY BE INCREASED BY .003 IN/ 0.08mm AFTER LEAD FINISH APPLIED.
- LEAD 1 IDENTIFICATION SHALL BE:
 - A NOTCH OR OTHER MARK WITHIN THIS AREA
 - A TAB ON LEAD 1, EITHER SIDE
- NO JEDEC REGISTRATION AS OF FEBRUARY 1996.

Revision History

Rev	ECN #	Rel Date	Originator	Changes
0CL	M0001741	02/11/99	Barbara Lopez	Changed: MNLM108A-X Rev. 0BL to MNLM108A-X Rev. 0CL. On IIB ₊ subgroup 3 was (-1.0min, 3.0max), corrected to read (-0.1min, 3.0max).
1A1	M0003235	02/11/99	Rose Malone	Updated MDS: MNLM108A-X, Rev. 0CL to MNLM108A-X, Rev. 1A1, Full Release. Added Pinout and B/I Ckt graphics and Thermal Data.